

4-bit GTL to GTL Transceiver

Features

- → Operates as a 4-bit GTL-/GTL/GTL+ to GTL-/GTL/GTL+ bus buffer
- → 2.3 V to 3.6 V operation
- → GTL input and output 3.6 V tolerant
- → Vref adjustable from 0.5 V to VCC/2
- → Partial power-down permitted
- → ESD protection exceeds 2000 V HBM per JESD22-A114 and 1000 V CDM per JESD22-CC101
- → Latch-up protection exceeds 200 mA per JESD78
- → Package offered: TSSOP14

Description

The GTL2034 is a 4-bit GTL-/GTL/GTL+ bus buffer. The GTL2034 GTL inputs and outputs operate up to 3.6 V, allowing the device to be used in higher voltage open-drain output applications.

Pin Configuration

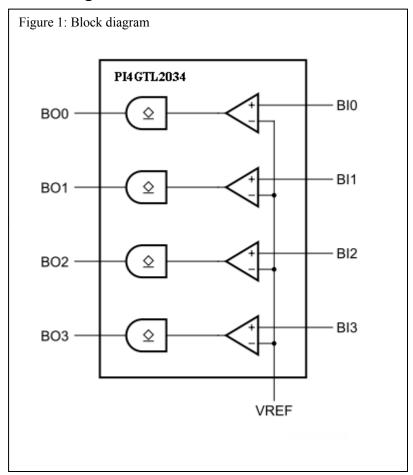
NC 1	14	VCC
BO0 2	13	BIO
BO1 3	12	BI1
VREF 4	11	GND
BO2 5	10	BI2
BO3 6	9	BI3
GND 7	8	GND
	l	

Pin Description

NC	1	not connected		
BO0	2	data outputs (GTL)		
BO1	3	(u u u u u u u.		
BO2	5			
BO3	6			
BI0	13	data inputs (GTL)		
BI1	12	1 (,		
BI2	10			
BI3	9			
VREF	4	GTL reference voltage		
GND	7,8,11	ground (0 V)		
VCC	14	positive supply voltage		



Block Diagram



Function Table:

BIx	BOx
Input	Output





Maximum Ratings

Power supply	0.5V to +4.6V
Voltage on an I/O pin	GND-0.5V to +4.6V
Supply current	±160mA
Ground supply current	400mA
Total power dissipation	
Operation temperature	-40~85°C
Storage temperature	-65~150°C
Maximum Junction temperature ,T j(max)	125°C
Total power dissipation	200mW

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Limiting Values

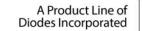
Symbol	Parameter	Conditions	Min.	Max.	Unit
VCC	Supply voltage		-0.5	4.6	V
I_{IK}	Input clamping current	VI <0V	-	-50	mA
V _I	Input voltage	B port	$-0.5^{[1]}$	4.6	V
I_{OK}	Output clamping current	VO <0V	-	-50	mA
Vo	Output voltage	output in OFF or HIGH state B port	$-0.5^{[1]}$	4.6	V
I_{OL}	LOW-level output current	B port	-	80	mA
Tstg	Storage temperature		^[2] -60	150	°C

Note:

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.







Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
VCC	Supply voltage		2.3	-	3.6	V
		Lowest voltage	0.71	0.75	0.79	V
V_{TT}	Termination voltage ^[1]	GTL-	0.85	0.9	0.95	V
		GTL	1.14	1.2	1.26	V
		GTL+	1.35	1.5	1.65	V
Vref	Reference voltage	overall	0.43	2/3V _{TT}	VCC/2	V
		Lowest voltage	0.43	0.5	0.55	
		GTL-	0.5	0.6	0.63	V
		GTL	0.76	0.8	0.84	V
		GTL+	0.87	1	1.1	V
V_{I}	Input voltage	B port	0	V_{TT}	3.6	V
$ m V_{IH}$	HIGH-level input voltage	B port	Vref + 0.050	-	-	V
V_{IL}	LOW-level input voltage	B port	-	-	Vref - 0.050	V
I_{OL}	LOW-level output current	B port	-	-	40	mA
Tamb	Ambient temperature	operating in free-air	-40	-	-85	°C

Note:

Static Characteristics

Recommended operating conditions; voltages are referenced to GND (ground = 0 V). $T_{amb} = -40 \,^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$

Symbol	Parameter	Conditions	Min.	Typ. ^[1]	Max.	Unit
V_{OL}	LOW-level output voltage	B port; VCC = 3.0 V; I _{OL} = 40 mA		0.23	0.4	V
		B port; VCC = 2.3 V; I _{OL} = 40 mA		0.26	0.4	V
$I_{\rm I}$	Input current	B port; VCC = 3.6 V ; V _I = V _{TT} or GND			±1	uA
I_{LO}	Output leakage current	B port; VCC = 3.6 V ; $V_0 = V_{TT}$			±1	uA
ICC	Quiescent supply current	B port; VCC = 3.6 V; V_I = VCC or GND; IO = 0 mA		4	8	mA
Ci	Input capacitance	B port; $VO = VTT$ or $0 V$		4.5		pF
Со	Input/output capacitance	B port; VO = VTT or 0 V	·	5.5		pF

Note:

^[1] V_{TT} maximum of 3.6 V with resistor sized so I_{OL} maximum is not exceeded.

^[1] All typical values are measured at VCC = 3.3 V and Tamb = $25 \,^{\circ}$ C.

^[2] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.





Dynamic Characteristics

All typical values are at VCC = 3.3 V and Tamb = 25 ° C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
GTL -; Vref =	GTL -; Vref = 0.5V; VTT = 0.75 V					
$t_{\rm PLH}$	LOW to HIGH	BIn to BOn;		3.5	8	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		6.5	10	ns
	propagation delay					
GTL - ; Vref =	0.6 V; VTT = 0.9 V					
$t_{\rm PLH}$	LOW to HIGH	BIn to BOn;		3.5	8	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		6.5	10	ns
	propagation delay					
GTL - ; Vref =	0.8 V; VTT = 1.2 V					
$t_{\rm PLH}$	LOW to HIGH	BIn to BOn;		4.1	8	ns
	propagation delay					
t_{PHL}	HIGH to LOW	BIn to BOn;		6.5	10	ns
	propagation delay					
GTL+; Vref = 1.0 V; VTT = 1.5 V						
$t_{\rm PLH}$	LOW to HIGH	BIn to BOn;		4.6	8	ns
	propagation delay					
t_{PHL}	HIGH to LOW	BIn to BOn;		6.5	10	ns
	propagation delay					

Dynamic Characteristics

All typical values are at VCC = 2.5 V and Tamb = 25 $^{\circ}$ C.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
GTL - ; Vref = 0	0.5V; $VTT = 0.75 V$					
t_{PLH}	LOW to HIGH	BIn to BOn;		4.2	8	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		8.6	12	ns
	propagation delay					
GTL - ; Vref = 0	0.6 V; VTT = 0.9 V					
$t_{\rm PLH}$	LOW to HIGH	BIn to BOn;		4.4	8	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		8.6	12	ns
	propagation delay					
GTL - ; $Vref = 0$).8 V; VTT = 1.2 V					
t_{PLH}	LOW to HIGH	BIn to BOn;		5.3	9	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		8.9	13	ns
	propagation delay					
GTL+; $Vref = 1.0 V$; $VTT = 1.5 V$						
t_{PLH}	LOW to HIGH	BIn to BOn;		6.5	10	ns
	propagation delay					
$t_{ m PHL}$	HIGH to LOW	BIn to BOn;		9.4	14	ns
	propagation delay					

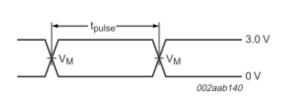


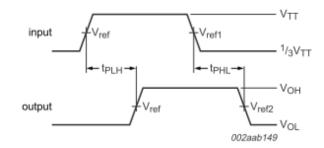
January 2018

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Waveforms

VM=Vref for B ports

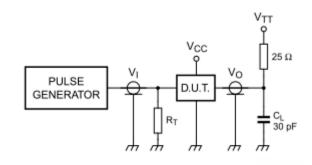




a. Pulse duration

b. Propagation delay times

Fig 2. Voltage waveforms



C_L = load capacitance; includes jig and probe capacitance.

R_T = termination resistance; should be equal to Z_o of pulse generator.

Fig 3. Load circuit for B outputs

Part Marking

L Package



YY: Year

WW: Workweek

1st X: Assembly Code

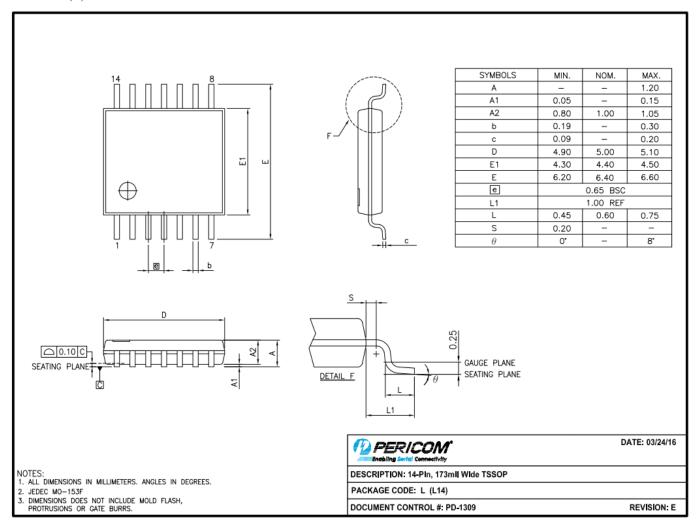
2nd X: Fab Code





Package Mechanical:

TSSOP-14(L)



For latest package info.

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Ordering Information

Part No.	Package Code	Description
PI4GTL2034LEX	L	14-Pin,173 mil Wide (TSSOP)

Notes:

- Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel





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ADG3245BCPZ ADG3247BRUZ ADG3247BRUZ-REEL ADG3248BKSZ-REEL7 ADG3257BRQZ-REEL ADG3304BCBZ-REEL7